

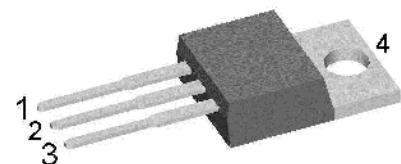
## Schottky Diode Gen 2

$V_{RRM}$  = 150 V  
 $I_{FAV}$  = 2x 10 A  
 $V_F$  = 0.73 V

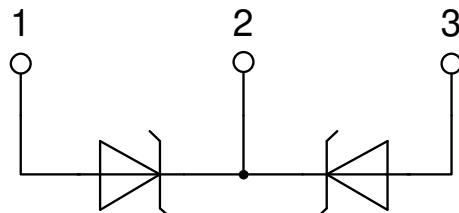
High Performance Schottky Diode  
 Low Loss and Soft Recovery  
 Common Cathode

**Part number**

**DSA20C150PB**



Backside: cathode



**Features / Advantages:**

- Very low  $V_F$
- Extremely low switching losses
- Low  $I_{rm}$  values
- Improved thermal behaviour
- High reliability circuit operation
- Low voltage peaks for reduced protection circuits
- Low noise switching

**Applications:**

- Rectifiers in switch mode power supplies (SMPS)
- Free wheeling diode in low voltage converters

**Package:** TO-220

- Industry standard outline
- RoHS compliant
- Epoxy meets UL 94V-0

**Disclaimer Notice**

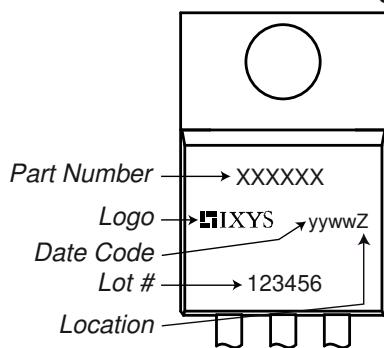
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**Schottky**

Symbol	Definition	Conditions	Ratings			
			min.	typ.	max.	
$V_{RSM}$	max. non-repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			150	V
$V_{RRM}$	max. repetitive reverse blocking voltage	$T_{VJ} = 25^\circ C$			150	V
$I_R$	reverse current, drain current	$V_R = 150 V$ $V_R = 150 V$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		200 2	$\mu A$ mA
$V_F$	forward voltage drop	$I_F = 10 A$ $I_F = 20 A$ $I_F = 10 A$ $I_F = 20 A$	$T_{VJ} = 25^\circ C$ $T_{VJ} = 125^\circ C$		0.87 0.98 0.73 0.85	V V V V
$I_{FAV}$	average forward current	$T_C = 155^\circ C$ rectangular $d = 0.5$	$T_{VJ} = 175^\circ C$		10	A
$V_{F0}$ $r_F$	threshold voltage slope resistance } for power loss calculation only		$T_{VJ} = 175^\circ C$		0.54 11.4	V mΩ
$R_{thJC}$	thermal resistance junction to case				2.4	K/W
$R_{thCH}$	thermal resistance case to heatsink				0.5	K/W
$P_{tot}$	total power dissipation	$T_C = 25^\circ C$			65	W
$I_{FSM}$	max. forward surge current	$t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}; V_R = 0 V$	$T_{VJ} = 45^\circ C$		220	A
$C_J$	junction capacitance	$V_R = 24 V$ f = 1 MHz	$T_{VJ} = 25^\circ C$		53	pF

**Package TO-220**

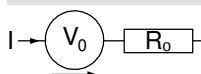
Symbol	Definition	Conditions	Ratings		
			min.	typ.	max.
$I_{RMS}$	RMS current	per terminal <sup>1)</sup>			35 A
$T_{VJ}$	virtual junction temperature		-55		175 °C
$T_{op}$	operation temperature		-55		150 °C
$T_{stg}$	storage temperature		-55		150 °C
<b>Weight</b>				2	g
$M_d$	mounting torque		0.4		0.6 Nm
$F_c$	mounting force with clip		20		60 N

**Product Marking**

**Part description**

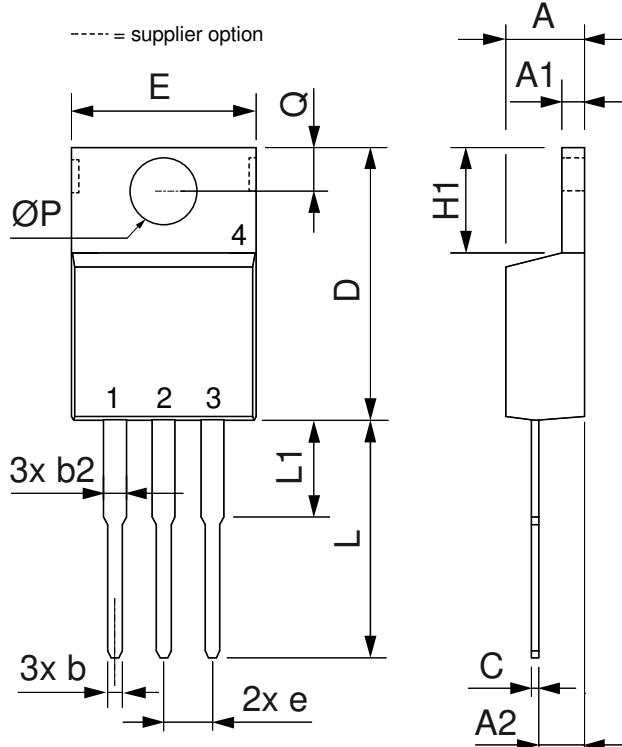
D = Diode  
S = Schottky Diode  
A = low VF  
20 = Current Rating [A]  
C = Common Cathode  
150 = Reverse Voltage [V]  
PB = TO-220AB (3)

Ordering	Ordering Number	Marking on Product	Delivery Mode	Quantity	Code No.
Standard	DSA20C150PB	DSA20C150PB	Tube	50	503913

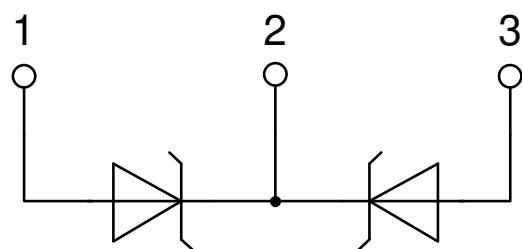
Similar Part	Package	Voltage class
DSA20C150PN	TO-220ABFP (3)	150

**Equivalent Circuits for Simulation**
<sup>\* on die level</sup>
 $T_{VJ} = 175^\circ\text{C}$ 

**Schottky**

$V_{0\ max}$	threshold voltage	0.54	$\text{V}$
$R_{0\ max}$	slope resistance *	8.2	

**Outlines TO-220**


Dim.	Millimeter		Inches	
	Min.	Max.	Min.	Max.
A	4.32	4.82	0.170	0.190
A1	1.14	1.39	0.045	0.055
A2	2.29	2.79	0.090	0.110
b	0.64	1.01	0.025	0.040
b2	1.15	1.65	0.045	0.065
C	0.35	0.56	0.014	0.022
D	14.73	16.00	0.580	0.630
E	9.91	10.66	0.390	0.420
e	2.54	BSC	0.100	BSC
H1	5.85	6.85	0.230	0.270
L	12.70	13.97	0.500	0.550
L1	2.79	5.84	0.110	0.230
ØP	3.54	4.08	0.139	0.161
Q	2.54	3.18	0.100	0.125



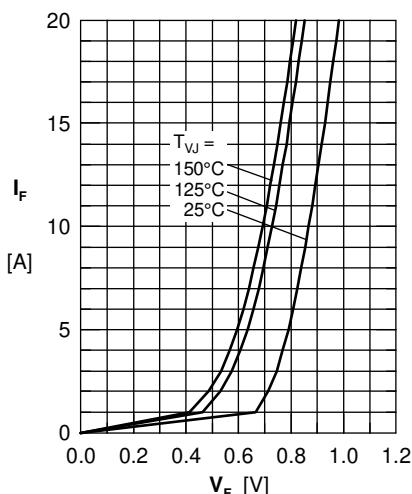
**Schottky**


Fig. 1 Maximum forward voltage drop characteristics

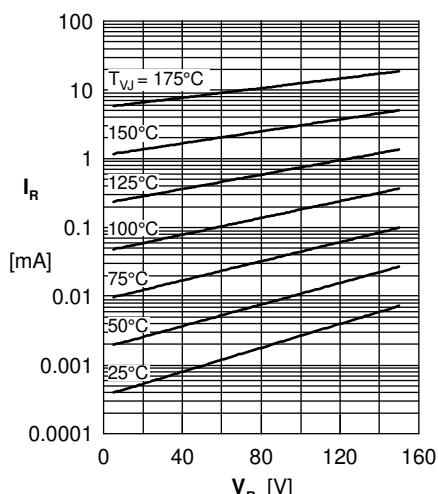


Fig. 2 Typ. reverse current  $I_R$  vs. reverse voltage  $V_R$

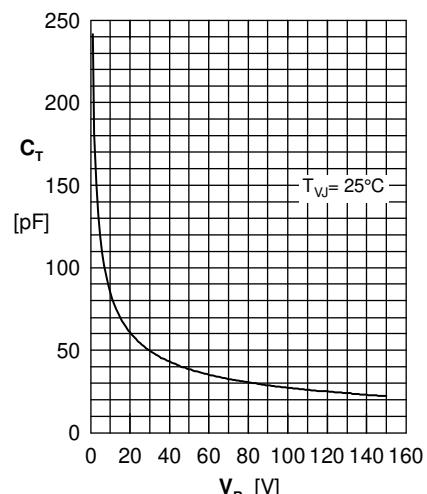


Fig. 3 Typ. junction capacitance  $C_T$  versus reverse voltage  $V_R$

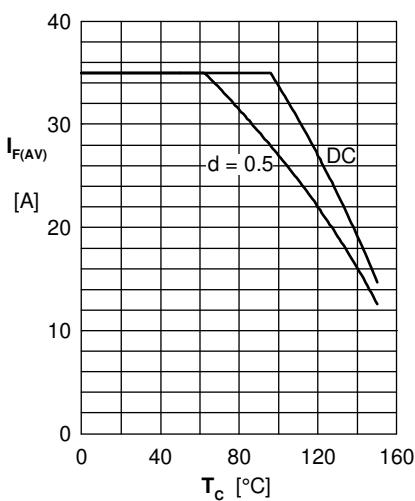


Fig. 4 Avg: forward current  $I_{F(\text{AV})}$  vs. case temperature  $T_C$

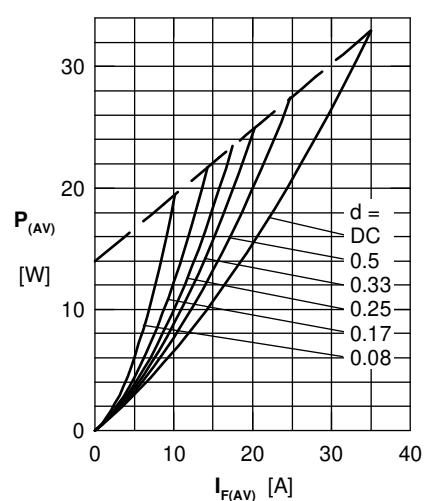


Fig. 5 Forward power loss characteristics

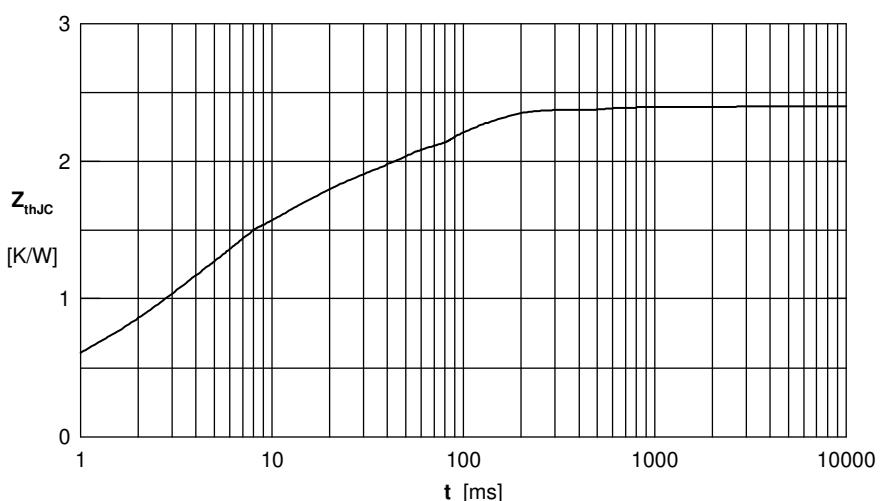


Fig. 6 Transient thermal impedance junction to case